



复旦微电子

FM11NT021

***NFC Forum Type2 Tag compliant IC with
144 bytes user memory***

Datasheet

Jul. 2020

INFORMATION IN THIS DOCUMENT IS INTENDED AS A REFERENCE TO ASSIST OUR CUSTOMERS IN THE SELECTION OF SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD PRODUCT BEST SUITED TO THE CUSTOMER'S APPLICATION; THEY DO NOT CONVEY ANY LICENSE UNDER ANY INTELLECTUAL PROPERTY RIGHTS, OR ANY OTHER RIGHTS, BELONGING TO SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD OR A THIRD PARTY.

WHEN USING THE INFORMATION CONTAINED IN THIS DOCUMENTS, PLEASE BE SURE TO EVALUATE ALL INFORMATION AS A TOTAL SYSTEM BEFORE MAKING A FINAL DECISION ON THE APPLICABILITY OF THE INFORMATION AND PRODUCTS.

PURCHASERS ARE SOLELY RESPONSIBLE FOR THE CHOICE, SELECTION AND USE OF THE SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD PRODUCTS AND SERVICES DESCRIBED HEREIN, AND SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD ASSUMES NO LIABILITY WHATSOEVER RELATING TO THE CHOICE, SELECTION OR USE OF THE SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD PRODUCTS AND SERVICES DESCRIBED HEREIN. UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD REPRESENTATIVE, SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE.

FUTURE ROUTINE REVISIONS WILL OCCUR WHEN APPROPRIATE, WITHOUT NOTICE. CONTACT SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD SALES OFFICE TO OBTAIN THE LATEST SPECIFICATIONS AND BEFORE PLACING YOUR PRODUCT ORDER. PLEASE ALSO PAY ATTENTION TO INFORMATION PUBLISHED BY SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD BY VARIOUS MEANS, INCLUDING SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD HOME PAGE ([HTTP://WWW.FMSH.COM/](http://www.fms.com/)).

PLEASE CONTACT SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD LOCAL SALES OFFICE FOR THE SPECIFICATION REGARDING THE INFORMATION IN THIS DOCUMENT OR SHANGHAI FUDAN MICROELECTRONICS GROUP CO., LTD PRODUCTS.

Trademarks

Shanghai Fudan Microelectronics Group Co., Ltd name and logo, the “复旦” logo are trademarks or registered trademarks of Shanghai Fudan Microelectronics Group Co., Ltd or its subsidiaries in China.

Shanghai Fudan Microelectronics Group Co., Ltd, Printed in the China, All Rights Reserved.



Contents

| | |
|--|-----------|
| CONTENTS..... | 3 |
| 1 PRODUCT OVERVIEW..... | 4 |
| 1.1 INTRODUCTION..... | 4 |
| 1.2 FEATURES | 4 |
| 1.2.1 RF Interface..... | 4 |
| 1.2.2 EEPROM | 4 |
| 1.2.3 NFC Forum Tag 2 Type compliance..... | 4 |
| 1.2.4 Security | 5 |
| 1.3 BLOCK DIAGRAM..... | 6 |
| 1.4 PIN DESCRIPTION | 6 |
| 1.4.1 Bumping Pin Description..... | 6 |
| 1.4.2 TDFN4..... | 7 |
| 1.4.3 SD function | 7 |
| 2 FUNCTIONAL DESCRIPTION..... | 8 |
| 2.1 GENERAL DESCRIPTION | 8 |
| 2.2 MEMORY ORGANIZATION | 8 |
| 2.2.1 UID | 9 |
| 2.2.2 Lock bytes | 9 |
| 2.2.3 CC bytes..... | 10 |
| 2.2.4 Initial memory configuration..... | 10 |
| 2.2.5 Configuration block..... | 10 |
| 2.3 SPECIAL FUNCTION | 12 |
| 2.3.1 Read times counter..... | 12 |
| 2.3.2 Password protection | 12 |
| 2.4 COMMAND SET | 13 |
| 2.4.1 READ..... | 13 |
| 2.4.2 FAST_READ | 14 |
| 2.4.3 WRITE..... | 14 |
| 2.4.4 READ_CNT..... | 15 |
| 2.4.5 PWD_AUTH | 15 |
| 2.4.6 ACK and NAK..... | 16 |
| 3 CHARACTERISTICS | 17 |
| 3.1 LIMITING VALUES..... | 17 |
| 3.2 WORKING CONDITION..... | 17 |
| 3.3 ELECTRICAL CHARACTERISTICS | 17 |
| 3.4 EEPROM CHARACTERISTICS | 17 |
| 4 PACKAGE INFORMATION..... | 18 |
| 4.1 TDFN4 | 18 |
| 5 ORDERING INFORMATION..... | 19 |
| REVISION HISTORY..... | 20 |
| SALES AND SERVICE | 21 |

1 Product Overview

1.1 Introduction

FM11NT021 is primarily designed for NFC Forum Type 2 Tag applications. Please consult Fudan Microelectronics Company for more documents.

1.2 Features

1.2.1 RF Interface

- ISO/IEC 14443A
- Contactless transmission of data and supply energy (no battery needed)
- Operating distance: up to 100 mm (depending on various parameters as e.g. field strength and antenna geometry)
- Operating frequency: 13.56 MHz
- Fast data transfer: 106 Kbit/s
- High data integrity: 16-bit CRC, parity, bit coding, bit counting
- 7 byte UID (cascade level 2 according to ISO/IEC 14443-3)
- Fast read command
- Read times counter function

1.2.2 EEPROM

- user memory: 144 bytes (36 pages)
- 4 bytes initialized capability container with one time programmable access bits
- Field programmable read-only locking function per page for the first 16 pages
- Field programmable read-only locking function above the first 16 pages per double page
- Data retention of 10 years
- Write endurance 500,000 cycles

1.2.3 NFC Forum Tag 2 Type compliance

FM11NT021 provides full compliance to the NFC Forum Type 2 Tag technical specification and enables NDEF data structure configuration.



1.2.4 Security

- Manufacturer programmed 7-byte UID for each chip
- Anti-tearing support for capability container (CC) and lock bits
- Field programmable read-only locking function

1.3 Block Diagram

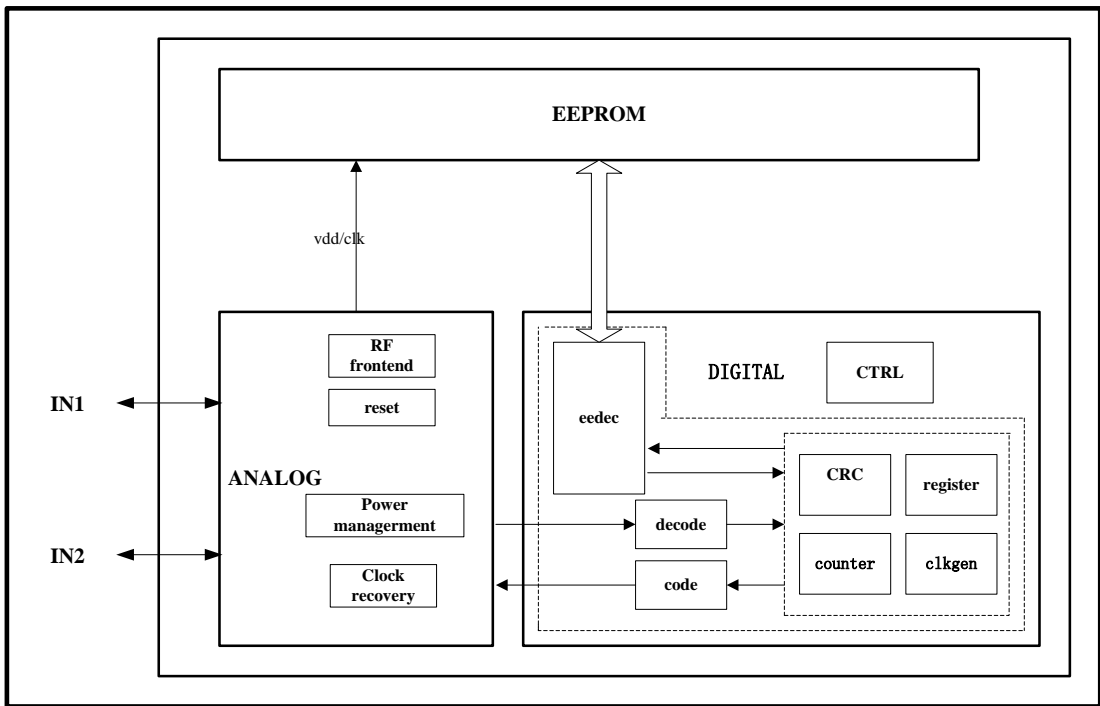


Figure 1-1 FM11NT021 Block diagram

1.4 Pin Description

1.4.1 Bumping Pin Description

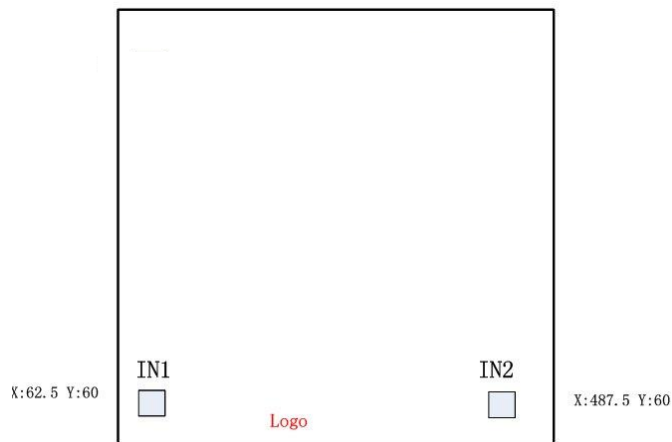


Figure 1-2 Bumping Pin Description

| Number | Pin name | Description |
|--------|----------|--------------------|
| 1 | IN1 | Antenna Connection |
| 2 | IN2 | Antenna Connection |

1.4.2 TDFN4

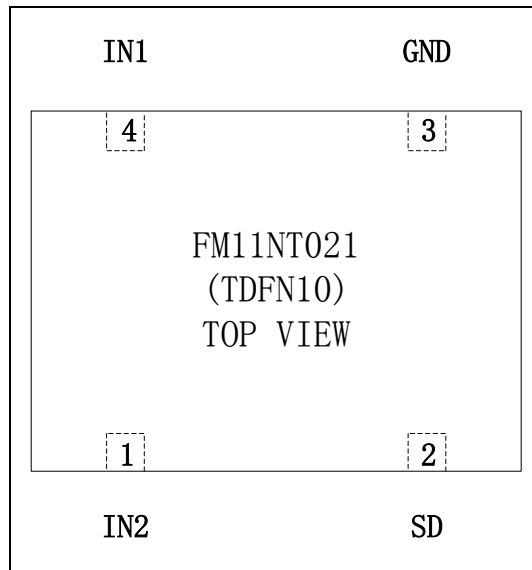


Figure 1-3 TDFN4 Pin Description

| Number | Bumping pin name | Description |
|--------|------------------|--|
| 1 | IN2 | Antenna Connection |
| 2 | SD | Selected detection signal output, open drain |
| 3 | GND | Ground pin |
| 4 | IN1 | Antenna Connection |

1.4.3 SD function

FM11NT021 has chip selected detection function. SD pin is open drain and a pull up resistor is needed. When the chip is selected by the reader, the SD pin will change from high to low. This signal can be used to wake up an off-chip MCU.

2 Functional Description

2.1 General Description

FM11NT021 chip has an 180bytes EEPROM memory embedded. FM11NT021 contains the RF-Interface and the Digital Control Unit. Energy and data are transferred via an antenna, which consists of a coil with a few turns directly connected to the IN1 and IN2 of the FM11NT021.

2.2 Memory Organization

- EEPROM: 180 bytes, organized in 45 pages of 4 byte per page.
 - 26 bytes reserved for manufacturer and configuration data
 - 34 bits used for the read-only locking mechanism
 - 4 bytes available as capability container
 - 144 bytes user programmable read/write memory

Table 2-1 FM11NT021 Memory organization

| Page No | | Byte Number inside a page | | | |
|---------|-----|---|----------|-----------|-----------|
| DEC | HEX | 0 | 1 | 2 | 3 |
| 0 | 0h | Serial Number | | | |
| 1 | 1h | Serial Number | | | |
| 2 | 2h | Serial Number | Internal | Lock Byte | Lock Byte |
| 3 | 3h | Capability Container (CC) | | | |
| 4 | 4h | TLV | | | |
| 5 | 5h | | | | |
| ... | ... | Static Data Area (Page4-15) | | | |
| 15 | Fh | | | | |
| 16 | 10h | | | | |
| ... | ... | Dynamic Data Area (Page 16-39, total 24blocks) | | | |
| 40 | 28h | Dynamic Lock Bytes | | | |
| 41 | 29h | RFU | RFU | RFU | AUTH0 |
| 42 | 2Ah | ACCESS | REGU_CFG | RFU | |
| 43 | 2Bh | PWD | | | |
| 44 | 2Ch | PACK | | RFU | |
| 45 | 2Dh | 24bit Counter | | | RFU |

2.2.1 UID

The unique 7 byte serial number (UID) and its two Block Check Character Bytes (BCC) are programmed into the first 9 bytes of the memory. It covers page 00h, page 01h and the first byte of page 02h. The second byte of page 02h is reserved for internal data. Due to security and system requirements these bytes are write-protected after the programming during the IC production.

According to ISO/IEC 14443-3, BCC0 is defined as CT SN0 SN1 SN2. An ABBREVIATION CT stays for Cascade Tag byte (88h) and BCC1 is defined as SN3 SN4 SN5 SN6. SN0 holds the Manufacturer ID for Fudan Microelectronics (1Dh) according to ISO/IEC 14443-3 and ISO/IEC 7816-6 AMD.1.

2.2.2 Lock bytes

Lock bytes enable the user to lock parts of the complete memory area for writing. A Read from user memory area cannot be restricted via lock bytes functionality. The lock bytes functionality is enabled with a WRITE command, where 2 out of 4 bytes transmitted are used for setting the lock bytes.

2.2.2.1 Static Lock

The bits of byte 2 and byte 3 of page 02h represent the field programmable read-only locking mechanism. Each page from 03h (CC) to 0Fh can be individually locked by setting the corresponding locking bit Lx to logic 1 to prevent further write access. After locked, the corresponding page becomes read-only memory.

The three least significant bits of lock byte 0 are the block-locking bits. Bit 2 deals with pages 0Ah to 0Fh, bit 1 deals with pages 04h to 09h and bit 0 deals with page 03h (CC). Once the block-locking bits are set, the locking configuration for the corresponding memory area is frozen.

Table 2-2 Lock0 (Block 02, Byte2)

| BIT | 7 (MSB) | 6 | 5 | 4 | 3 | 2 | 1 | 0 (LSB) |
|--|------------|---|---|---|----|-------------|-----------|------------|
| Locked Block Number (Decimal) | 7 | 6 | 5 | 4 | CC | BL 15~10 | BL 9~4 | BL CC |

Table 2-3 Lock1 (Block 02, Byte3)

| BIT | 7 (MSB) | 6 | 5 | 4 | 3 | 2 | 1 | 0 (LSB) |
|--|------------|----|----|----|----|----|---|------------|
| Locked Block Number (Decimal) | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 |

For example if BL15-10 is set to logic 1, then bits L15 to L10 (lock byte 1, bit [7:2]) can no longer be changed. The so called static locking and block-locking bits are set by a WRITE command to page 02h. Bytes 2 and 3 of the WRITE command and the contents of the lock bytes are bit-wise



OR'ed and the result then becomes the new content of the lock bytes. This process is irreversible. If a bit is set to logic 1, it cannot be changed back to logic 0. The contents of bytes 0 and 1 of page 02h are unaffected by the corresponding data bytes of the WRITE command. The default value of the static lock bytes is 0000h. Any write operation to the static lock bytes is tearing-proof.

2.2.2.2 Dynamic Lock

The dynamic lock bytes are used to lock the pages starting at page address 10h. The lock bytes are located at page 28h. The three lock bytes cover the memory area of 96 data bytes for FM11NT021. The granularity is 2 pages.

The default value of the dynamic lock bytes is 00 00 00h. The value of Byte 3 is always BDh when read. Any write operation to the dynamic lock bytes is tearing-proof.

2.2.3 CC bytes

The Capability Container CC (page 3) is programmed according to the NFC Forum Type 2 Tag specification Ref. 8. You can change these bytes by a WRITE command.

The content that needs to be written in will be OR'ed with the current contents of the CC bytes. The result will replace the old contents in CC area. This process is irreversible. If a bit is set to "1", it cannot be changed back to "0" again.

2.2.4 Initial memory configuration

The page 03h, 04h and 05h of FM11NT021 are initialized according to the NFC Forum Type 2 Tag specification.

Table 2-4 Initial memory organization of FM11NT021

| Page Address | Byte0 | Byte1 | Byte2 | Byte3 |
|--------------|-------|-------|-------|-------|
| 03h | E1h | 10h | 12h | 00h |
| 04h | 01h | 03h | A0h | 0Ch |
| 05h | 34h | 03h | 00h | FEh |

2.2.5 Configuration block

2.2.5.1 Overview

FM11NT021's 29h~2Ch store the configuration information:

Table 2-5 Configuration area

| Page address | Byte0 | Byte1 | Byte2 | Byte3 |
|--------------|--------|-------|-------|-------|
| 29h | RFU | RFU | RFU | AUTH0 |
| 2Ah | ACCESS | RFU | RFU | RFU |
| 2Bh | PWD | | | |



| Page address | Byte0 | Byte1 | Byte2 | Byte3 |
|--------------|----------------|-------|-------|-------|
| 2Ch | PACK | | RFU | RFU |
| 2Dh | 24bits Counter | | | RFU |

2.2.5.2 ACCESS

Table 2-6 Access byte

| Name: ACCESS | | | |
|--------------|--|--------|--------|
| Field | Description | Reset | Access |
| 7 | PROT Definition of what will be protected by the password ◇ 0: Write operation need password check firstly ◇ 1: Write and read operation all need password check firstly | 0 | RW |
| 6 | CFGLOCK The lock bits of the configuration area (only lock the lowest 2 pages) ◇ 0: The configuration area can be changed ◇ 1: The configuration area cannot be changed permanently | 0 | RW |
| 5 | RFU | | |
| 4 | NFC_CNT_EN ◇ 0: Counter function is disabled ◇ 1: Counter function is enabled | 0 | RW |
| 3 | NFC_CNT_PWD_PROT ◇ 0: Counter function is not protected by the password ◇ 1: Counter function is under the protection of the password | 0 | RW |
| 2:0 | AUTHLIM The up limit of the password check error times ◇ 000: no limit ◇ 001-111: the maximum times of the check error | 3'b000 | RW |

2.2.5.3 AUTH0

Table 2-7 AUTH0

| Name: AUTH0 | | | |
|-------------|--|-------|--------|
| Field | Description | Reset | Access |
| 7:0 | AUTH0 Definition of the start page address which need to be protected by the password | 8'hFF | RW |

2.2.5.4 PWD

Table 2-8 PWD



| Name: PWD | | | |
|-----------|---|--------------|--------|
| Field | Description | Reset | Access |
| 31:0 | PWD 32bits password, unreadable in the user mode It is recommended to set the PWD under the protection of AUTH0 | 32'hFFFFFFFF | RW |

2.2.5.5 PACK

Table 2-9 PACK Byte

| Name: PACK | | | |
|------------|---|----------|--------|
| Field | Description | Reset | Access |
| 15:0 | PACK The response of password verification PACK will be sent back when the password in PWD_AUTH command is the same to the stored password. Otherwise, NAK will be sent back. It is recommended to set the PACK under the protection of AUTH0. | 16'h0000 | RW |

2.3 Special Function

2.3.1 Read times counter

FM11NT021 has a read times counter function. Once the tag is read by the READ command or FAST-READ command, the 24bits counter's value will be added automatically.

This function can be enabled or disabled with the NFC_CNT_EN bit. The actual counter value can be read by READ_CNT command.

The reading of the Counter can also be protected with the password authentication. The Counter password protection is enabled or disabled with the NFC_CNT_PWD_PROT bit.

2.3.2 Password protection

The read and write authority to the specific address of the memory can be controlled by the password which stored in the EEPROM (4bytes). The response which is 2 bytes is also stored in the EEPROM. User can change them all by themselves.

AUTHLIM is used to define the up limit of the failed password check times. If the error times is out of the limit value, the chip will not response to the check request anymore.

AUTH0's default value is FFh that main the password protection function has been shutdown. User can turn it on after the confiuration. The memory of EEPROM will be protected by the password whose address is starting from the AUTH0.

2.4 Command set

FM11NT021's command is following ISO/IEC14443-A.

Table 2-10 Command overviews

| Command | Command code (hexadecimal) |
|-------------------|-------------------------------|
| Request | 26h (7 bit) |
| Wake-up | 52h (7 bit) |
| Anticollision CL1 | 93h 20h |
| Select CL1 | 93h 70h |
| Anticollision CL2 | 95h 20h |
| Select CL2 | 95h 70h |
| Halt | 50h 00h |
| READ | 30h |
| FAST_READ | 3Ah |
| WRITE | A2h |
| READ_CNT | 39h |
| PWD_AUTH | 1Bh |

2.4.1 READ

The READ command is used to read 16bytes data from the memory of FM11NT021 at a time. The data is the 4 pages that start from the address in the command's parameter.

Table 2-11 READ command

| Name | Code | Description | Length |
|------|----------------|-------------------------------------|----------|
| Cmd | 30h | read four pages | 1 byte |
| Addr | - | start page address | 1 byte |
| CRC | - | CRC according to ISO/IEC14443 | 2 bytes |
| Data | - | Data content of the addressed pages | 16 bytes |
| NAK | see Table 2-21 | see Section 2.4.6 | 4-bit |

The timing is according to ISO/IEC 14443-3 frame specification.

Table 2-12 READ timing

| | T _{ACK/NAK} min | T _{ACK/NAK} max | T _{TimeOut} |
|------|--------------------------|--------------------------|----------------------|
| READ | n=9 | T _{TimeOut} | 5 ms |

2.4.2 FAST_READ

The FAST_READ command is used to read more than 16bytes data quickly. The data is all of the pages between the start address and the end address.

Table 2-13 FAST_READ command

| Name | Code | Description | Length |
|-----------|----------------|-------------------------------------|-----------|
| Cmd | 3Ah | read multiple pages | 1 byte |
| StartAddr | - | start page address | 1 byte |
| EndAddr | - | end page address | 1 byte |
| CRC | - | CRC according to ISO/IEC14443 | 2 bytes |
| Data | - | data content of the addressed pages | n*4 bytes |
| NAK | see Table 2-21 | see Section 2.4.6 | 4-bit |

The timing is according to ISO/IEC 14443-3 frame specification.

Table 2-14 FAST_READ timing

| | T _{ACK/NAK} min | T _{ACK/NAK} max | T _{TimeOut} |
|-----------|--------------------------|--------------------------|----------------------|
| FAST_READ | n=9 | T _{TimeOut} | 5 ms |

2.4.3 WRITE

The WRITE command is used to writes 4 bytes of data into the addressed FM11NT021's page.

Table 2-15 WRITE command

| Name | Code | Description | Length |
|------|----------------|-------------------------------|---------|
| Cmd | A2h | write one page | 1 byte |
| Addr | - | page address | 1 byte |
| CRC | - | CRC according to ISO/IEC14443 | 2 bytes |
| Data | - | data | 4 bytes |
| NAK | see Table 2-21 | see Section 2.4.6 | 4-bit |

The timing is according to ISO/IEC 14443-3 frame specification.

Table 2-16 WRITE timing

| | T _{ACK/NAK} min | T _{ACK/NAK} max | T _{TimeOut} |
|--|--------------------------|--------------------------|----------------------|
| | | | |

| | | | |
|-----------|-----|----------------------|------|
| FAST_READ | n=9 | T _{TimeOut} | 5 ms |
|-----------|-----|----------------------|------|

2.4.4 READ_CNT

The READ_CNT command is used to read out the current value of the 24 bits counter.

Table 2-17 READ_CNT command

| Name | Code | Description | Length |
|------|----------------|-------------------------------|---------|
| Cmd | 39h | read counter | 1 byte |
| Addr | 02h | page address | 1 byte |
| CRC | - | CRC according to ISO/IEC14443 | 2 bytes |
| Data | - | counter value | 3 bytes |
| NAK | see Table 2-21 | see Section 2.4.6 | 4-bit |

The timing is according to ISO/IEC 14443-3 frame specification.

Table 2-18 READ_CNT timing

| | T _{ACK/NAK min} | T _{ACK/NAK max} | T _{TimeOut} |
|----------|--------------------------|--------------------------|----------------------|
| READ_CNT | n=9 | T _{TimeOut} | 5 ms |

2.4.5 PWD_AUTH

PWD_AUTH is used to check the password which protects the area defined by AUTH0.

Table 2-19 PWD_AUTH command

| Name | Code | Description | Length |
|------|----------------|-------------------------------------|---------|
| Cmd | 1Bh | password authentication | 1 byte |
| Addr | - | password | 4 bytes |
| CRC | - | CRC according to ISO/IEC14443 | 2 bytes |
| Data | - | password authentication acknowledge | 2 bytes |
| NAK | see Table 2-21 | see Section 2.4.6 | 4-bit |

The timing is according to ISO/IEC 14443-3 frame specification.



Table 2-20 PWD_AUTH timing

| | T _{ACK/NAK min} | T _{ACK/NAK max} | T _{TimeOut} |
|----------|--------------------------|--------------------------|----------------------|
| READ_CNT | n=9 | T _{TimeOut} | 5 ms |

2.4.6 ACK and NAK

FM11NT021 uses a 4 bit ACK / NAK:

Table 2-21 ACK and NAK values

| Code (4-bit) | ACK/NAK |
|--------------|--|
| Ah | Acknowledge (ACK) |
| 0h | NAK for invalid argument (i.e. invalid page address) |
| 1h | NAK for parity or CRC error |
| 4h | NAK for invalid authentication counter overflow |
| 5h | NAK for EEPROM write error |

FM11NT021 replies to a Select CL2 command with 44h which is transmitted with the least significant byte first.

3 Characteristics

3.1 Limiting values

| Parameter | Min | Max | Unit |
|----------------------------|-----|------|------|
| storage temperature | -55 | +125 | °C |
| input current (IN1 to IN2) | - | ±30 | mA |
| ESD (HBM) 【2】 | - | ±4 | KV |

Table 3-1 FM11NT021 Limiting values 【1】

【1】 Stresses above one or more of the limiting values may cause permanent damage to the device.

【2】 Human body model: C = 100 pF, R = 1.5 k

3.2 Working Condition

| Symbol | Parameter | Min | Typ | Max | Unit |
|----------------|----------------|-----|-----|-----|------|
| T _A | Temperature | -40 | +25 | +85 | °C |
| H _A | Field strength | 1.5 | | 7.5 | A/M |

Table 3-2 FM11NT021 Working Condition

3.3 Electrical characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|-----------------------|---------------------|--------|-------|--------|------|
| f _i | input frequency | | 13.553 | 13.56 | 13.567 | MHz |
| C _i | input capacitance 【1】 | Between IN1 and IN2 | | 50 | | pF |

Table 3-3 Electrical characteristics

【1】 Measured with Agilent E5061B, the frequency is 13.56MHz, RMS voltage is 0.707V.

3.4 EEPROM characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------------|-----------------|-------------------------|--------|-----|-----|-------|
| t _{ret} | retention time | T _{amb} = 55°C | 10 | | | year |
| N _{endu(W)} | write endurance | T _{amb} = 25°C | 500000 | | | cycle |

Table 3-4 EEPROM characteristics

4 Package information

4.1 TDFN4

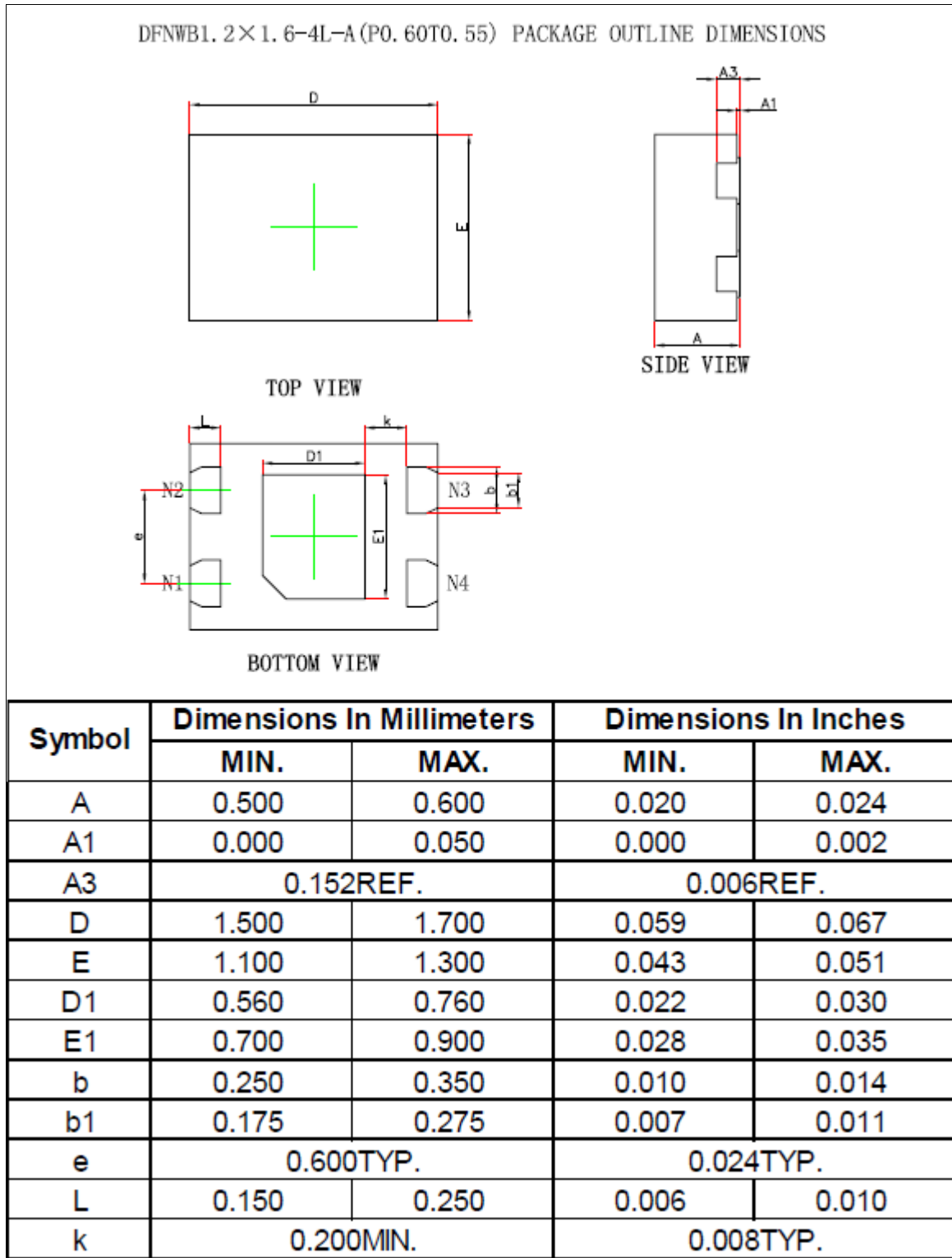
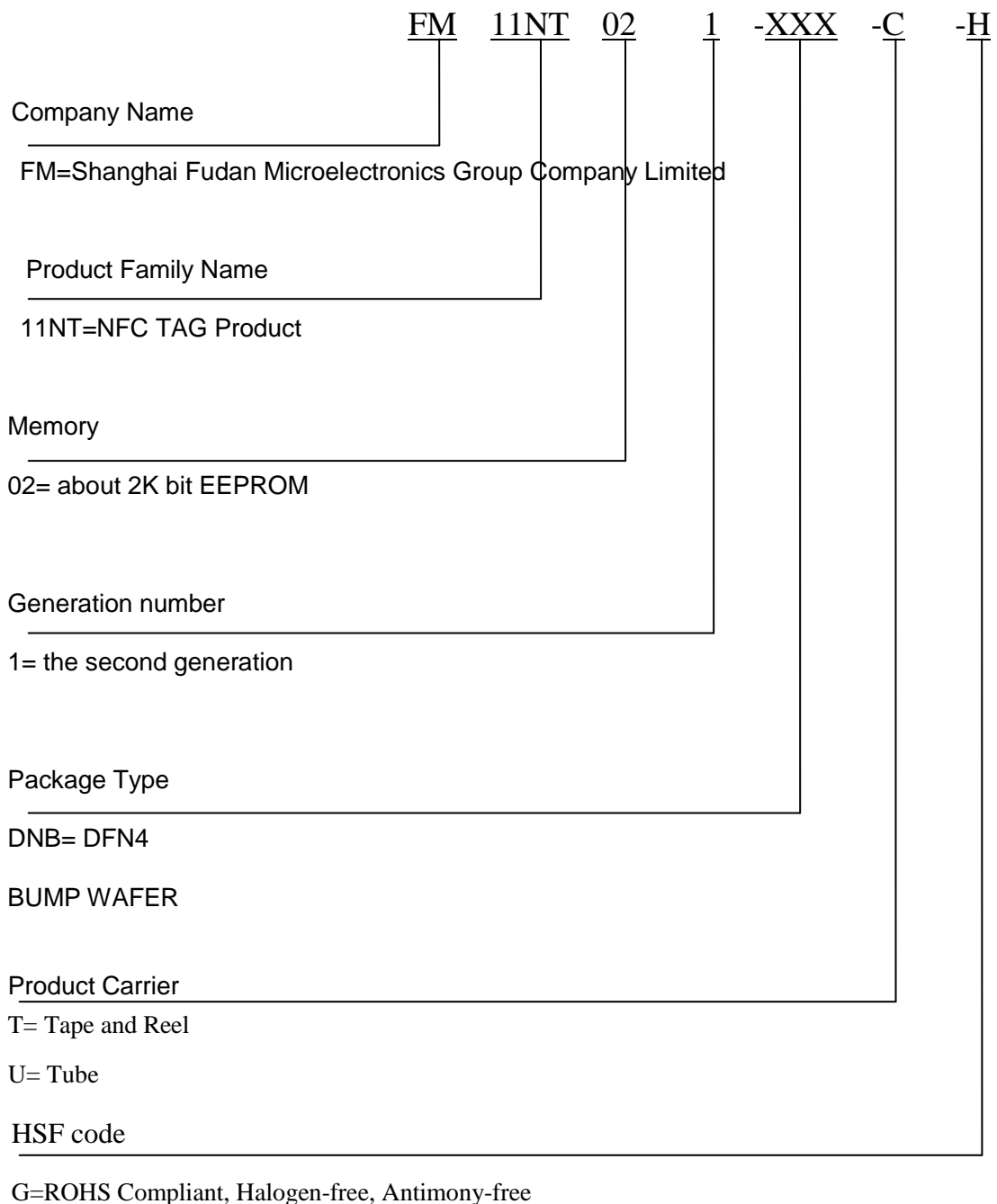


Figure 4-2 DFN4 package size



5 Ordering information

| Type Number | Wafer Type | Description |
|-------------------|-----------------|---|
| FM11NT021-DNB-T-G | TDFN4 | Reel package |
| FM11NT021-WIB2 | Bump Sawn Wafer | 8 inch bump wafer (120um thickness, without UV exposure, on film frame carrier; electronic fail die marking according to SECSII format) |





Revision history

| Version | Publication date | Pages | Paragraph or Illustration | Revise Description |
|---------|------------------|-------|---------------------------|--|
| 1.0 | Jul. 2020 | 23 | | New datasheet for the new chip version |
| | | | | |



Sales and Service

Shanghai Fudan Microelectronics Group Co., Ltd.

Address: Bldg No. 4, 127 Guotai Rd,
Shanghai City China.

Postcode: 200433

Tel: (86-021) 6565 5050

Fax: (86-021) 6565 9115

Shanghai Fudan Microelectronics (HK) Co., Ltd.

Address: Unit 506, 5/F., East Ocean Centre, 98 Granville Road, Tsimshatsui East, Kowloon, Hong Kong

Tel: (852) 2116 3288 2116 3338

Fax: (852) 2116 0882

Beijing Office

Address: Room 423, Bldg B, Gehua Building,
1 QingLong Hutong, Dongzhimen Alley north Street,
Dongcheng District, Beijing City, China.

Postcode: 100007

Tel: (86-010) 8418 6608

Fax: (86-010) 8418 6211

Shenzhen Office

Address: Room.1301, Century Bldg, No. 4002, Shengtingyuan Hotel, Huaqiang Rd (North),
Shenzhen City, China.

Postcode: 518028

Tel: (86-0755) 8335 0911 8335 1011 8335 2011 8335 0611

Fax: (86-0755) 8335 9011

Shanghai Fudan Microelectronics (HK) Ltd Taiwan Representative Office

Address: Unit 1225, 12F., No 252, Sec.1 Neihu Rd., Neihu Dist., Taipei City 114, Taiwan

Tel : (886-2) 7721 1889

Fax: (886-2) 7722 3888

Shanghai Fudan Microelectronics (HK) Ltd Singapore Representative Office

Address : 237, Alexandra Road, #07-01 The Alexcier, Singapore 159929

Tel : (65) 6472 3688

Fax: (65) 6472 3669

Shanghai Fudan Microelectronics Group Co., Ltd NA Office

Address :2490 W. Ray Road Suite#2

Chandler, AZ 85224 USA

Tel : (480) 857-6500 ext 18

Web Site: <http://www.fmsb.com/>